



Features and Benefits

- LAPT (High frequency multi emitter transistor)
- Small package (TO-3P)
- High power handling capacity, 160 W
- Improved sound output by reduced on-chip impedance
- For professional audio (PA) applications, V_{CEO} = -260 V versions available
- Complementary to 2SC6145
- Recommended output driver: 2SA1668A

Package: 3-Lead TO-3P



Not to scale

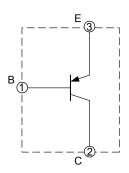
Description

Sanken LAPT transistors have an innovative design, produced by adapting advancements in the unique Sanken thin-wafer production technology. These PNP power transistors achieve faster power-up by decreasing thermal resistance, and provide a higher avalanche breakdown voltage rating. The high power-handling capacity of the TO-3P package allows a smaller footprint on the circuit board layout. This series of transistors is very well suited not only for multichannel applications for AV (audio-visual) amplifiers and receivers, but also for parallel connection applications for PA (professional audio system) amplifiers.

Applications include the following:

- Single transistors for audio amplifiers
- Home audio amplifiers
- Professional audio amplifiers
- Automobile audio amplifiers
- Audio market
- Single transistors for general purpose

Equivalent Circuit



w2SA2223

Audio Amplification Transistor

Selection Guide

Part Number	Туре	h _{FE} Rating	Packing
		Range R: 40 to 80	
2SA2223*	PNP	Range O: 50 to 100	30 pieces per tube
		Range Y: 70 to 140	

^{*}Specify h_{FE} range when ordering.

Absolute Maximum Ratings at T_A = 25°C

Characteristic	Symbol	Remarks	Rating	Unit
Collector-Base Voltage	V _{CBO}		-230	V
Collector-Emitter Voltage	V _{CEO}		-230	V
Emitter-Base Voltage	V _{EBO}		- 5	V
Collector Current	Ic		-15	А
Base Current	I _B		-4	Α
Collector Power Dissipation	Pc	T _{CASE} = 25°C	160	W
Junction Temperature	TJ		150	°C
Storage Temperature	T _{stg}		-55 to150	°C

ELECTRICAL CHARACTERISTICS at T_A = 25°C

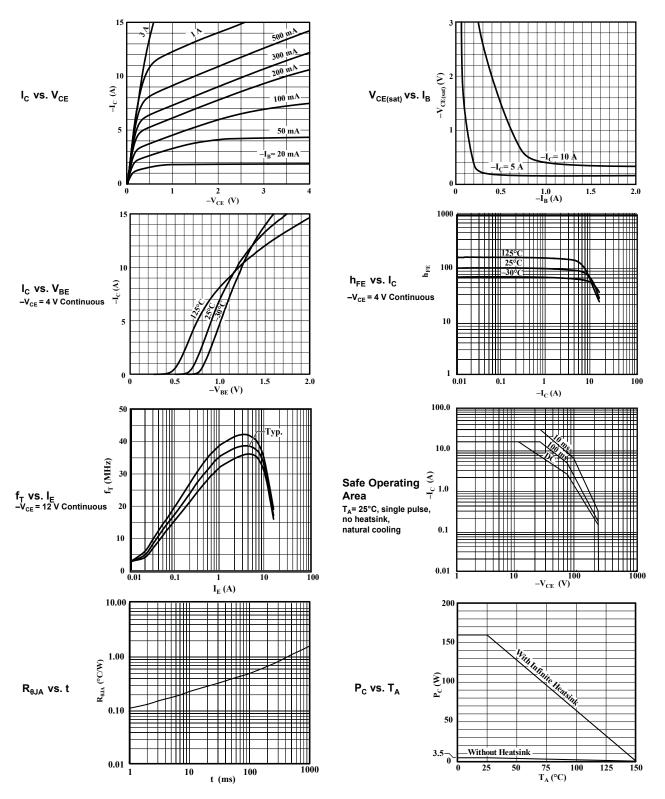
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Collector-Cutoff Current	I _{CBO}	V _{CB} = -230 V	-	_	-10	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} = -5 V	-	-	-10	μΑ
Collector-Emitter Voltage	V _{(BR)CEO}	I _C = -25 mA	-230	-	-	V
DC Current Transfer Ratio*	h _{FE}	V _{CE} = -4 V, I _C = -5 A	40	_	140	-
Collector-Emitter Saturation Voltage	V _{CE(sat)}	$I_C = -5 \text{ A}, I_B = -0.5 \text{ A}$	_	-	-0.5	V
Cutoff Frequency	f _T	V _{CE} = -12 V, I _E = 2 A	-	35	_	MHz
Output Capacitance	C _{OB}	V _{CB} = -10 V, I _E = 0 A, f = 1 MHz	_	500	_	pF

^{*}h_{FE} rating: 40 to 80 (R brand on package), 50 to 100 (O), 70 to 140 (Y).





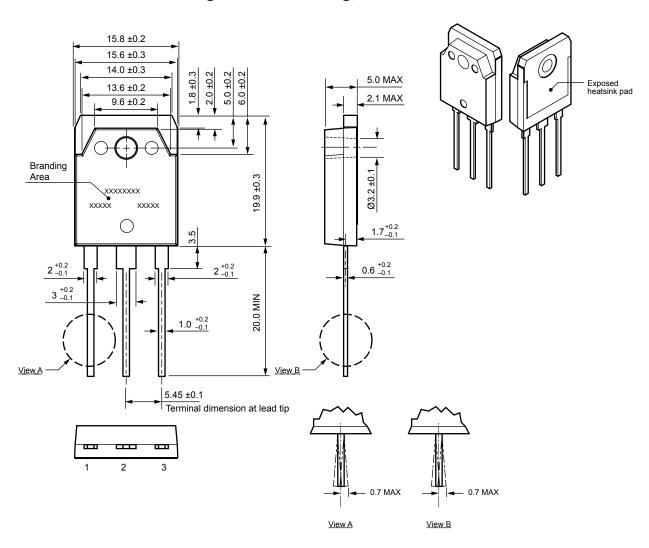
Performance Characteristics







Package Outline Drawing, TO-3P



Gate burr: 0.3 mm (max.), mold flash may appear at opposite side

Terminal core material: Cu

Terminal treatment: Ni plating and Pb-free solder dip

Leadform: 100

Package: TO-3P (M100) Approximate weight: 6 g

Dimensions in millimeters

Branding codes (exact appearance at manufacturer discretion):

1st line, type: A2223 2nd line left, lot: *YM*

Where: Y is the last digit of the year of manufacture

M is the month (1 to 9, O, N, D)

2nd line right, subtype: H

Where: H is the h_{FE} rating (*O, R,* or *Y*; for values see footnote, Electrical Characteristics table)



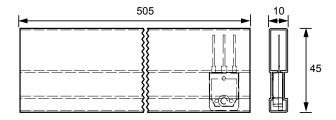
Leadframe plating Pb-free. Device composition includes high-temperature solder (Pb >85%), which is exempted from the RoHS directive.

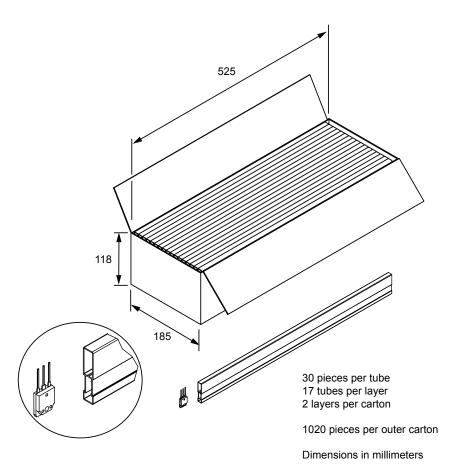




Packing Specification

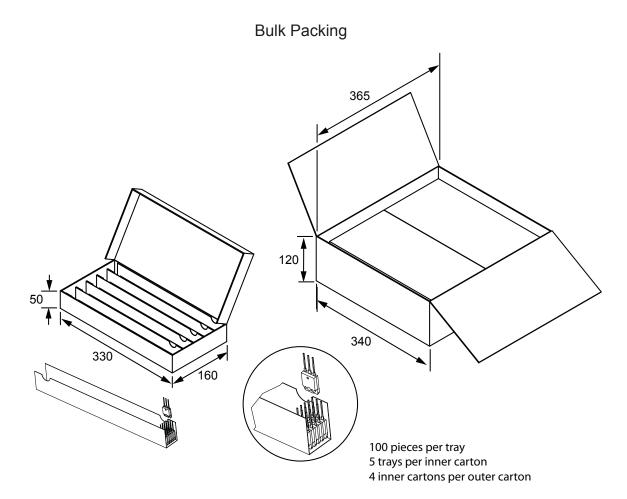
Tube Packing











500 pieces maximum per inner carton 2000 pieces maximum per outer carton

Dimensions in millimeters





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Audio Amplification Transistor

WARNING — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between adjacent products, and shorts to the heatsink.

Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting this product on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce stress.
- Coat the back surface of the product and both surfaces of the insulating plate to improve heat transfer between the product and the heatsink.
- Volatile-type silicone greases may permeate the product and produce cracks after long periods of time, resulting in reduced heat radiation effect, and possibly shortening the lifetime of the product.
- Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Type		Suppliers
	G746	Shin-Etsu Chemical Co., Ltd.
	YG6260	Momentive Performance Materials
	SC102	Dow Corning Toray Silicone Co., Ltd.

Heatsink Mounting Method

- Torque When Tightening Mounting Screws. Thermal resistance increases when tightening torque is low, and radiation effects are decreased. When the torque is too high, the screw can strip, the heatsink can be deformed, and distortion can arise in the product frame. To avoid these problems, observe the recommended tightening torques for this product package type, TO-3P (MT-100): 0.686 to 0.882 N·m (7 to 9 kgf•cm).
- Diameter of Heatsink Hole: < 4 mm. The deflection of the press mold when making the hole may cause the case material to crack at the joint with the heatsink. Please pay special attention for this effect.

Soldering

 When soldering the products, please be sure to minimize the working time, within the following limits:

260±5°C 10 s 350±5°C 3 s

 Soldering iron should be at a distance of at least 1.5 mm from the body of the products

Electrostatic Discharge

- When handling the products, operator must be grounded. Grounded wrist straps worn should have at least 1 M Ω of resistance to ground to prevent shock hazard.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in other to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in our shipping containers or conductive containers, or be wrapped in aluminum foil.





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Audio Amplification Transistor

The products described herein are manufactured in Japan by Sanken Electric Co., Ltd. for sale by Allegro MicroSystems, Inc.

Sanken and Allegro reserve the right to make, from time to time, such departures from the detail specifications as may be required to permit improvements in the performance, reliability, or manufacturability of its products. Therefore, the user is cautioned to verify that the information in this publication is current before placing any order.

When using the products described herein, the applicability and suitability of such products for the intended purpose shall be reviewed at the users responsibility.

Although Sanken undertakes to enhance the quality and reliability of its products, the occurrence of failure and defect of semiconductor products at a certain rate is inevitable.

Users of Sanken products are requested to take, at their own risk, preventative measures including safety design of the equipment or systems against any possible injury, death, fires or damages to society due to device failure or malfunction.

Sanken products listed in this publication are designed and intended for use as components in general-purpose electronic equipment or apparatus (home appliances, office equipment, telecommunication equipment, measuring equipment, etc.). Their use in any application requiring radiation hardness assurance (e.g., aerospace equipment) is not supported.

When considering the use of Sanken products in applications where higher reliability is required (transportation equipment and its control systems or equipment, fire- or burglar-alarm systems, various safety devices, etc.), contact a company sales representative to discuss and obtain written confirmation of your specifications.

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Anti radioactive ray design is not considered for the products listed herein.

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